LV5725JA

Bi-CMOS LSI Step-down Switching Regulator



150

°C

Overview

The LV5725JA is a step-down voltage switching regulator.

Functions

- Wide input dynamic range: 4.5V to 50V.
- Built-in pulse-by-pulse OCP circuit: detection is on resistance of an external MOS.
- Over current protection: HICCUP mode.
- Load-independent soft start circuit
- Synchronous operation by external signal.
- External voltage is usable when output voltage is high.

Specifications

Maximum junction temperature

Absolute Maximum Ratings at Ta = 25°C

Parameter Conditions Symbol Ratings Unit v Supply voltage 55 VIN max VIN, SW, OUT, PGOOD 55 v HDRV, CBOOT 61 V Allowable pin voltage LDRV 6.0 v Between CBOOT to SW v 6.0 Between CBOOT to HDRV EN, ILIM V_{IN}+0.3 v Between VIN to ILIM 1.0 v VDD 6.0 v SS, FB, COMP, RT, SYNC V_{DD}+0.3 v Pd max W Allowable Power dissipation Mounted on a specified board. 1.45 Operating temperature -40 to +85 °C Topr Storage temperature Tstg -55 to +150 °C Parameter Symbol Conditions Ratings Unit

Specified board : 58.0mm × 78.0mm × 1.6mm, fiberglass epoxy printed board.

Tj max

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current,

high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Current mode type.
- - Thermal shutdown.
 - ON/OFF pin
 - · Power good pin

LV5725JA

Recommended Operating Range at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage range	VIN		4.5 to 50	V
Error amplifier input voltage	V _{FB}		0 to 1.6	V
Oscillatory frequency	FOSC		50 to 500	kHz

Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{IN} = 12V$

Parameter	Symbol	Conditions	Ratings			Unit
	Cymbol	Conditione	min	typ	max	01m
Reference voltage block			·			
Internal reference voltage	Vref	Including offset of E/A	0.698	0.708	0.718	V
5V power supply	V _{DD}	I _{OUT} = 0 to 5mA	4.7	5.2	5.7	V
Triangular waveform oscillator block						
Oscillation frequency	FOSC	RT= 56kΩ	317	365	412	kHz
Frequency variation	FOSC DV	V _{IN} = 4.5 to 50V		1		%
Fold back detection voltage	VOSC FB	After power is supplied to SS, voltage is detected FB.		0.5		V
Fold back oscillation frequency	FOSC FB	RT= 56kΩ, V _{FB} = 0V	100	130	160	kHz
ON/OFF circuit block						
IC start-up voltage	V_{EN} on		-	2.5	3.0	V
Hysteresis of startup voltage	V _{EN} hys		0.3	0.6	-	V
Soft start circuit block						
Soft start source current	I _{SS} SC	EN > 3.0V	4	5	6	μA
Soft start sink current	I _{SS} SK	EN < 1V, V _{DD} = 5V		2		mA
Soft start end voltage	V _{SS} END		0.7	0.9	1.1	V
UVLO circuit block						
UVLO voltage	V _{UVLO}		3.7	4.0	4.3	V
Hysteresis of UVLO	V _{UVLO} H			0.3		V
Error amplifier						
Input bias current	IEA IN				100	nA
Error amplifier gain	G _{EA}		1000	1400	1800	μΑ/\
Range of common-mode input voltage	V _{EA R}	V _{IN} = 4.5 to 50V	0		1.6	V
Output sink current	IEA OSK	FB = 1.0V		-100		μA
Output source current	IEA OSC	FB = 0V		100		μA
Current detection amplifier gain	GISNS			2.4		
Over current limiter circuit block						
Reference current	ILIM		-10%	20	+10%	μA
Over current detection comparator offset voltage	V _{LIM_OFS}		-5		+5	mV
Range of over current detection	V _{LIM_CM}		V _{IN} -0.45		V _{IN}	V
comparator common mode input	_					
PWM comparator	1		· · ·			
Input threshold voltage	Vt max	Duty cycle = D _{MAX} , SW = V _{IN}	1.15	1.25	1.35	V
	Vt0	Duty cycle = 0%, SW = V_{IN}	0.5	0.6	0.7	V
Maximum ON duty	D _{MAX}		92			%

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	Symbol	Conditions	Ratings			
Parameter			min	typ	max	Unit
Power good						
Power good "L" sink current	IPGL	PGOOD = 5V		5		mA
Power good "H" sink current	I _{PG} H	PGOOD = 5V			1	μΑ
Power good voltage	PG _{thresh}	When FB voltage rises		0.612		V
Hysteresis of power good	PG _{hys}			12		mV
Output block	• -	·				
High side output ON resistance (upper)	R _{ONH} _HIGH	CBOOT – HDRV = -0.1V		12		Ω
High side output ON resistance (lower)	R _{ONL} _HIGH	HDRV – SW = +0.1V		3.3		Ω
Low side output ON resistance (upper)	R _{ONH} LOW	$V_{DD} - LDRV = -0.1V$		7.9		Ω
Low side output ON resistance (lower)	R _{ONL} LOW	LDRV – GND = +0.1V		3.8		Ω
High side output ON current (upper)	I _{ONH_} HIGH	CBOOT – HDRV = -4.5V	160			mA
High side output ON current (lower)	I _{ONL_} HIGH	HDRV – SW = +4.5V	330			mA
Low side output ON current (upper)	I _{ONH_} LOW	V _{DD} – LDRV = -5.2V	190			mA
Low side output ON current (lower)	I _{ONL_} LOW	LDRV – GND = +5.2V	250			mA
Entire device	•	•				
Standby current	ICCS	EN < 1V			1	μA
Average current consumption	ICCA	EN > 3.0V		2.5		mA

Package Dimensions

unit : mm (typ) 3178B





Block Diagram



Sample application circuit



Pin Assignment



Pin Function

Pin No.	Pin name	Description
1	COMP	Error amplifier output pin. Make sure to connect a phase compensation network between COMP and GND.
2	RT	Oscillating frequency setting pin. Make sure to connect a resistor between this pin and GND.
3	SYNC	External synchronous signal input pin.
4	PGOOD	Power good pin.
5	EN	ON/OFF pin.
6	SW	This pin is connected to switching node. Connect the source of Nch MOSFET to this pin.
7	СВООТ	Bootstrap capacitor connected pin. This pin is used as gate driving power supply for external Nch MOSFET. Make sure to connect a capacitor between CBOOT and SW.
8	HDRV	External upper MOSFET gate driving pin.
9	LDRV	External lower MOSFET gate driving pin.
10	OUT	Internal regulator power supply pin. This pin is connected to VOUT.
11	V _{DD}	Power supply pin for gate drive of the external lower MOS-FET.
12	GND	Ground pin. GND pin voltage is the reference for each reference voltage.
13	VIN	Power supply pin. This pin is monitored by UVLO function. When the voltage of this pin becomes higher than 4.3V by UVLO function, the IC starts up and mode shifts to soft start operation.
14	ILIM	Reference current pin for current detection. The inlet current of approx. 20µA flows into this pin. Connect a resistor externally between this pin and VIN and when the voltage supplied to SW pin is lower than the pin voltage of this resistor, the upper Nch MOSFET is turned off by current limiter comparator. This operation is reset at every PWM pulse.
15	SS/HICCUP	Capacitor connection pin for soft start. This pin enables to charge the soft start capacitor by 5µA. (approx) When this pin turns approx. 0.9V, soft start period ends and frequency fold back function is activated.
16	FB	Error amplifier reverse input pin. Converter operates to set this pin to 0.708V. The output voltage divided by the external resistance is applied to this pin. After soft start, frequency fold back function operates when the voltage of this pin becomes 0.5V or lower. And oscillating frequency decreases together with FB voltage.

I/O pin equivalent circuit chart

Pin No.	Pin No.	Equivalent Circuit		
1	СОМР	$V_{DD} (1) $ $Z k \Omega$ $COMP (1) $ $U = 1$ $U $		
2	RT	VDD (1) $10k\Omega$ RT (2) 500Ω 500Ω FT GND (2)		
3	SYNC	VDD (1) SYNC (3) SYNC (3) GND (12)		
4	PGOOD	V _{DD} (1) PGOOD (4) ↓ 1kΩ ↓ 1kΩ ↓ 1kΩ		
5	EN	VDD (1) FN (5) $(462k\Omega 365k\Omega + 650k\Omega + $		
6	SW	CBOOT \overline{O} V_{IN} \overline{O}		

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Pin No.	Pin No.	Equivalent Circuit
7	CBOOT	$V_{DD} (1) \longrightarrow W_{DC}$ $CBOOT (7) \longrightarrow W_{IN} (13) \longrightarrow W_{IN} ($
8	LDRV	CBOOT (7 HDRV (8) SW (6) GND (2)
9	HDRV	
10	OUT	
11	V _{DD}	
12, 13	GND, V _{IN}	
14	ILIM	VIN (13 CRUE CRUE CRUE CRUE CRUE CRUE CRUE CRUE

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Pin No.	Pin No.	Equivalent Circuit
15	SS/HICCUP	VDD (1) SSS/HICCUP (5) GND (2) VDD (1) (1) (1) (2) (3) (3) (4) (5) (4) (5) (5) (6) (6) (7) (7) (7) (7) (7) (7) (7) (7
16	FB	V _{DD} (1) FB (6) GND (2) VDD (1) FB (6) FB (6) FB (6) FB (6) FB (7) FB (7)

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